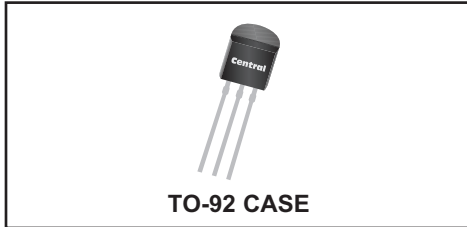


PN918

NPN SILICON RF TRANSISTOR



DESCRIPTION:

The CENTRAL SEMICONDUCTOR PN918 type is an NPN silicon RF transistor, manufactured by the epitaxial planar process and designed for high frequency amplifier and oscillator applications.

MARKING: FULL PART NUMBER

MAXIMUM RATINGS: ($T_A=25^\circ\text{C}$ unless otherwise noted)

	SYMBOL		UNITS
Collector-Base Voltage	V_{CBO}	30	V
Collector-Emitter Voltage	V_{CEO}	15	V
Emitter-Base Voltage	V_{EBO}	3.0	V
Continuous Collector Current	I_C	50	mA
Power Dissipation	P_D	625	mW
Power Dissipation ($T_C=25^\circ\text{C}$)	P_D	1.0	W
Operating and Storage Junction Temperature	T_J, T_{stg}	-65 to +150	$^\circ\text{C}$
Thermal Resistance	θ_{JA}	2.0	$^\circ\text{C/W}$
Thermal Resistance	θ_{JC}	12.5	$^\circ\text{C/W}$

ELECTRICAL CHARACTERISTICS: ($T_A=25^\circ\text{C}$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
I_{CBO}	$V_{CB}=15\text{V}$		10	nA
BV_{CBO}	$I_C=1.0\mu\text{A}$	30		V
BV_{CEO}	$I_C=3.0\text{mA}$	15		V
BV_{EBO}	$I_E=10\mu\text{A}$	3.0		V
$V_{CE(SAT)}$	$I_C=10\text{mA}, I_B=1.0\text{mA}$		0.4	V
$V_{BE(SAT)}$	$I_C=10\text{mA}, I_B=1.0\text{mA}$		1.0	V
h_{FE}	$V_{CE}=1.0\text{V}, I_C=3.0\text{mA}$	20		
f_T	$V_{CE}=10\text{V}, I_C=4.0\text{mA}, f=100\text{MHz}$	600		MHz
C_{ob}	$V_{CB}=10\text{V}, I_E=0, f=1.0\text{MHz}$		1.7	pF
C_{ob}	$V_{EB}=0, I_E=0, f=1.0\text{MHz}$		3.0	pF
C_{ib}	$V_{EB}=0.5\text{V}, I_C=0, f=1.0\text{MHz}$		2.0	pF
P_o	$V_{CB}=15\text{V}, I_C=8.0\text{mA}, f=500\text{MHz}$	30		mW
G_{pe}	$V_{CB}=12\text{V}, I_C=6.0\text{mA}, f=200\text{MHz}$	15		dB
η	$V_{CB}=15\text{V}, I_C=8.0\text{mA}, f=500\text{MHz}$	25		%
NF	$V_{CE}=6.0\text{V}, I_C=1.0\text{mA}, R_G=400\Omega, f=60\text{kHz}$		6.0	dB

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TO-92 CASE - MECHANICAL OUTLINE



R1

SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A (DIA)	0.175	0.205	4.45	5.21
B	0.170	0.210	4.32	5.33
C	0.500	-	12.70	-
D	0.016	0.022	0.41	0.56
E	0.100		2.54	
F	0.050		1.27	
G	0.125	0.165	3.18	4.19
H	0.080	0.105	2.03	2.67
I	0.015		0.38	

TO-92 (REV: R1)

LEAD CODE:

- 1) Emitter
- 2) Base
- 3) Collector

**MARKING:
FULL PART NUMBER**

R0 (11-September 2012)